

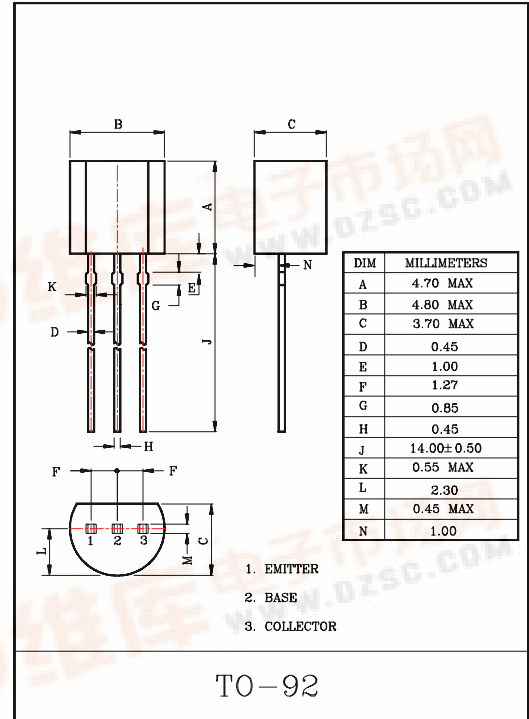
HIGH FREQUENCY APPLICATION.  
HF, VHF BAND AMPLIFIER APPLICATION.

### FEATURE

- High Power Gain :  $G_{pe}=29\text{dB(Typ.)}$  at  $f=10.7\text{MHz}$ .

### MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	35	V
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	50	mA
Emitter Current	$I_E$	-50	mA
Collector Power Dissipation	$P_C$	625	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55~150	°C



### ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=35\text{V}, I_E=0$	-	-	0.1	$\mu\text{A}$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=4\text{V}, I_C=0$	-	-	0.1	$\mu\text{A}$
DC Current Gain	$h_{FE}$ (Note)	$V_{CE}=5\text{V}, I_C=1\text{mA}$	40	-	198	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=1\text{mA}$	-	-	0.4	V
Transition Frequency	$f_T$	$V_{CB}=10\text{V}, I_C=1\text{mA}, f=100\text{MHz}$	100	-	400	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$	-	2.0	-	pF

Note :  $h_{FE}$  Classification E:40~59, F:54~80, G:72~108, H:97~146, I:132~198